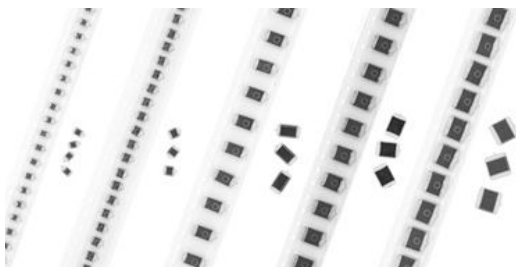


Solid Tantalum Chip Capacitors TANTAMOUNT[®], Low Profile, Conformal Coated

Application Specific Pulse Capacitor for Wireless Modems



FEATURES

- Robust design for use in wireless modem applications
- Designed specifically for pulsed operation
- 100 % surge current tested
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

PERFORMANCE CHARACTERISTICS

www.vishay.com/doc?40088

Operating Temperature: - 55 °C to + 125 °C
(above 40 °C, voltage derating is required)

Capacitance Tolerance: ± 20 % standard

Capacitance Range: 330 µF to 2200 µF

Voltage Rating: 6.3 V_{DC} to 10 V_{DC}

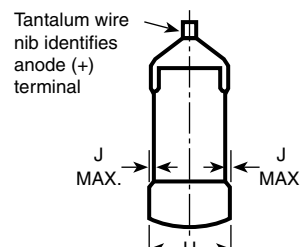
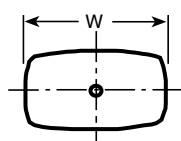
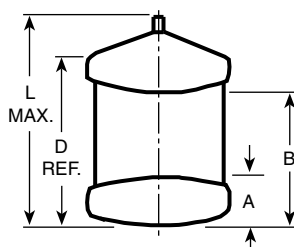
ORDERING INFORMATION

592W	757	X0	010	M	2	T	20H
TYPE	CAPACITANCE	CAPACITANCE TOLERANCE	DC VOLTAGE RATING AT + 85 °C	CASE CODE	TERMINATION	REEL SIZE AND PACKAGING	SUFFIX
	This is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow.	X0 = ± 20 %	This is expressed in volts. To complete the three-digit block, zeros precede the voltage rating. A decimal point is indicated by an "R" (6R3 = 6.3 V).	See Ratings and Case Codes table	2 = 100 % tin	T = 7" [178 mm] reel	Maximum height (mm) see dimensions

Note

- Preferred tolerance and reel sizes are in bold.
We reserve the right to supply higher voltage ratings and tighter capacitance tolerance capacitors in the same case size.

DIMENSIONS in inches [millimeters]



CASE CODE	SUFFIX	H	L MAX.	W	A	B	D REF.	J MAX.
C	16H	0.063 [1.6] max.	0.280 [7.1]	0.126 ± 0.012 [3.2 ± 0.3]	0.051 ± 0.012 [1.3 ± 0.3]	0.173 ± 0.024 [4.4 ± 0.6]	0.236 [6.0]	0.004 [0.1]
	20H	0.079 [2.0] max.						
M	20H	0.063 [1.6] max.	0.295 [7.5]	0.248 ± 0.012 [6.3 ± 0.3]	0.051 ± 0.012 [1.3 ± 0.3]	0.200 ± 0.024 [5.1 ± 0.6]	0.264 [6.7]	0.004 [0.1]
	20H	0.079 [2.0] max.						
X	16H	0.063 [1.6] max.	0.571 [14.5]	0.290 + 0.010/- 0.020 [7.37 + 0.25/- 0.5]	0.051 ± 0.016 [1.3 ± 0.4]	0.469 ± 0.024 [11.9 ± 0.6]	0.520 [13.2]	0.004 [0.1]
	20H	0.079 [2.0] max.						

**RATINGS AND CASE CODES**

μF	6.3 V	8.2 V	10 V
330			C_2.0
470	C_1.6	C_2.0	
680			
750			M_2.0
1000			X_2.0
1500		M_2.0 ⁽¹⁾	
2200	X_1.6		

Note⁽¹⁾ Preliminary value, contact factory for availability**STANDARD RATINGS**

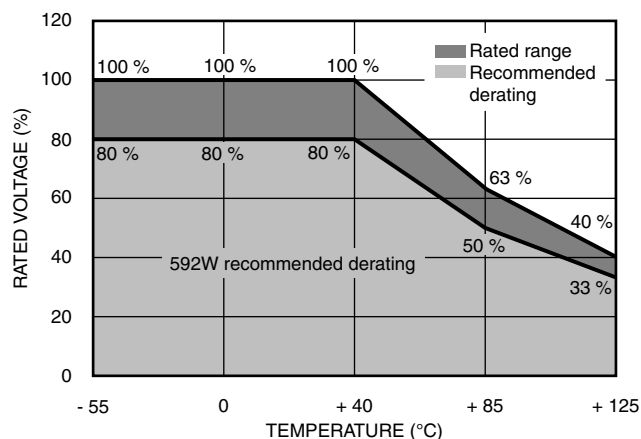
CAPACITANCE (μF)	CASE CODE	PART NUMBER	MAX. HEIGHT (mm)	MAX. DCL AT + 25 °C (μA)	MAX. DF AT + 25 °C 120 Hz (%)	MAX. ESR AT + 25 °C 100 kHz (Ω)
6.3 V_{DC} AT + 40 °C; 4.0 V_{DC} AT + 85 °C; 2.5 V_{DC} AT + 125 °C						
470	C	592W477X06R3C2T16H	1.6	30	14	0.200
2200	X	592W228X06R3X2T16H	1.6	139	45	0.070
8.2 V_{DC} AT + 40 °C; 5.2 V_{DC} AT + 85 °C; 3.3 V_{DC} AT + 125 °C						
470	C	592W477X08R2C2T20H	2.0	57	20	0.100
1500	M ⁽¹⁾	592W158X08R2M2T20H	2.0	125	45	0.090
10 V_{DC} AT + 40 °C; 6.3 V_{DC} AT + 85 °C; 4.0 V_{DC} AT + 125 °C						
330	C	592W337X0010C2T20H	2.0	33	20	0.100
750	M	592W757X0010M2T20H	2.0	75	35	0.100
1000	X	592W108X0010X2T20H	2.0	100	35	0.080

Note⁽¹⁾ Preliminary value, contact factory for availability**ELECTRICAL PERFORMANCE CHARACTERISTICS**

ITEM	PERFORMANCE CHARACTERISTICS					
Category temperature range	- 55 °C to + 125 °C (with voltage derating)					
Capacitance tolerance	$\pm 20 \%$, $\pm 10 \%$ (at 120 Hz) 2 V _{RMS} at + 25 °C using a capacitance bridge					
Dissipation factor (at 120 Hz)	Limits per Standard Ratings table. Tested via bridge method, at 25 °C, 120 Hz					
ESR (100 kHz)	Limits per Standard Ratings table. Tested via bridge method, at 25 °C, 100 kHz					
Leakage current	After application of RV applied to capacitors for 5 min using a steady source of power with 1 k Ω resistor in series with the capacitor under test, leakage current at 25 °C is not more than described in.					
Operation temperatures	Rated voltage	- 55 °C/+ 40 °C	10 V	8.2 V	6.3 V	4.0 V
	Category voltage	+ 40 °C/+ 85 °C	6.3 V	5.2 V	4.0 V	2.5 V
	Category voltage	+ 85 °C/+ 125 °C	4 V	3.3 V	2.5 V	1.6 V



VOLTAGE VS. TEMPERATURE RATING



POWER DISSIPATION

CASE CODE	HEIGHT	MAXIMUM PERMISSIBLE POWER DISSIPATION AT + 25 °C (W) IN FREE AIR
C	16H	0.100
C	20H	0.110
M	20H	0.175
X	16H	0.170
X	20H	0.175

STANDARD PACKAGING QUANTITY

CASE CODE	HEIGHT	UNITS PER REEL, 7" REEL
C	Any	1000
M	Any	1000
X	Any	500

PRODUCT INFORMATION

Conformal Coated Guide	www.vishay.com/doc?40150
Pad Dimensions	
Packaging Dimensions	
Moisture Sensitivity	www.vishay.com/doc?40135
SELECTOR GUIDES	
Solid Tantalum Selector Guide	www.vishay.com/doc?49053
Solid Tantalum Chip Capacitors	www.vishay.com/doc?40091
FAQ	
Frequently Asked Questions	www.vishay.com/doc?40110



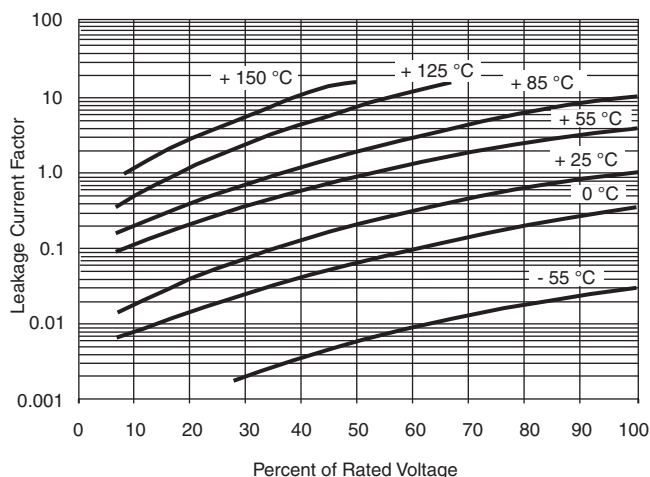
Typical Performance Characteristics Tantalum Capacitors

CAPACITOR ELECTRICAL PERFORMANCE CHARACTERISTICS				
ITEM	PERFORMANCE CHARACTERISTICS			
Category temperature range	- 55 °C to + 85 °C (to + 125 °C with voltage derating)			
Capacitance tolerance	± 20 %, ± 10 % (at 120 Hz) 2 V _{RMS} (max.) at + 25 °C using a capacitance bridge			
Dissipation factor	Limit per Standard Ratings table. Tested via bridge method, at 25 °C, 120 Hz			
ESR	Limit per Standard Ratings table. Tested via bridge method, at 25 °C, 100 kHz			
Leakage current	After application of rated voltage applied to capacitors for 5 min using a steady source of power with 1 kΩ resistor in series with the capacitor under test, leakage current at 25 °C is not more than 0.01 CV or 0.5 μA, whichever is greater. <i>Note that the leakage current varies with temperature and applied voltage. See graph below for the appropriate adjustment factor.</i>			
Capacitance change by temperature	+ 12 % max. (at + 125 °C) + 10 % max. (at + 85 °C) - 10 % max. (at - 55 °C)		For capacitance value > 300 μF + 20 % max. (at + 125 °C) + 15 % max. (at + 85 °C) - 15 % max. (at - 55 °C)	
Reverse voltage	Capacitors are capable of withstanding peak voltages in the reverse direction equal to: 10 % of the DC rating at + 25 °C 5 % of the DC rating at + 85 °C Vishay does not recommend intentional or repetitive application of reverse voltage			
Temperature derating	If capacitors are to be used at temperatures above + 25 °C, the permissible RMS ripple current or voltage shall be calculated using the derating factors: 1.0 at + 25 °C 0.9 at + 85 °C 0.4 at + 125 °C			
Operating temperature	+ 85 °C		+ 125 °C	
	RATED VOLTAGE (V)	SURGE VOLTAGE (V)	RATED VOLTAGE (V)	SURGE VOLTAGE (V)
	4	5.2	2.7	3.4
	6.3	8	4	5
	10	13	7	8
	16	20	10	12
	20	26	13	16
	25	32	17	20
	35	46	23	28
	50	65	33	40
	50 ⁽¹⁾	60	33	40
	63	76	42	50

Notes

- All information presented in this document reflects typical performance characteristics

⁽¹⁾ Capacitance values 15 μF and higher

**TYPICAL LEAKAGE CURRENT FACTOR RANGE****Notes**

- At + 25 °C, the leakage current shall not exceed the value listed in the Standard Ratings table.
- At + 85 °C, the leakage current shall not exceed 10 times the value listed in the Standard Ratings table.
- At + 125 °C, the leakage current shall not exceed 12 times the value listed in the Standard Ratings table.

CAPACITOR PERFORMANCE CHARACTERISTICS

ITEM	PERFORMANCE CHARACTERISTICS						
Surge voltage	<p>Post application of surge voltage (as specified in the table above) in series with a 33 Ω resistor at the rate of 30 s ON, 30 s OFF, for 1000 successive test cycles at 85 °C, capacitors meet the characteristics requirements listed below.</p> <table><tr><td>Capacitance change</td><td>Within ± 10 % of initial value</td></tr><tr><td>Dissipation factor</td><td>Initial specified value or less</td></tr><tr><td>Leakage current</td><td>Initial specified value or less</td></tr></table>	Capacitance change	Within ± 10 % of initial value	Dissipation factor	Initial specified value or less	Leakage current	Initial specified value or less
Capacitance change	Within ± 10 % of initial value						
Dissipation factor	Initial specified value or less						
Leakage current	Initial specified value or less						
Surge current	<p>After subjecting parts in series with a 1 Ω resistor at the rate of 3 s CHARGE, 3 s DISCHARGE, and a cap bank of 100K μF for 3 successive test cycles at 25 °C, capacitors meet the characteristics requirements listed below.</p> <table><tr><td>Capacitance change</td><td>Within ± 10 % of initial value</td></tr><tr><td>Dissipation factor</td><td>Initial specified value or less</td></tr><tr><td>Leakage current</td><td>Initial specified value or less</td></tr></table>	Capacitance change	Within ± 10 % of initial value	Dissipation factor	Initial specified value or less	Leakage current	Initial specified value or less
Capacitance change	Within ± 10 % of initial value						
Dissipation factor	Initial specified value or less						
Leakage current	Initial specified value or less						
Life test at + 85 °C	<p>Capacitors meet the characteristic requirements listed below. After 2000 h application of rated voltage at 85 °C.</p> <table><tr><td>Capacitance change</td><td>Within ± 10 % of initial value</td></tr><tr><td>Leakage current</td><td>Shall not exceed 125 % of initial value</td></tr></table>	Capacitance change	Within ± 10 % of initial value	Leakage current	Shall not exceed 125 % of initial value		
Capacitance change	Within ± 10 % of initial value						
Leakage current	Shall not exceed 125 % of initial value						
Life test at + 125 °C	<p>Capacitors meet the characteristic requirements listed below. After 1000 h application 2/3 of rated voltage at 125 °C.</p> <table><tr><td>Capacitance change for parts with cap. ≤ 600 μF</td><td>Within ± 10 % of initial value</td></tr><tr><td>for parts with cap. > 600 μF</td><td>Within ± 20 % of initial value</td></tr><tr><td>Leakage current</td><td>Shall not exceed 125 % of initial value</td></tr></table>	Capacitance change for parts with cap. ≤ 600 μ F	Within ± 10 % of initial value	for parts with cap. > 600 μ F	Within ± 20 % of initial value	Leakage current	Shall not exceed 125 % of initial value
Capacitance change for parts with cap. ≤ 600 μ F	Within ± 10 % of initial value						
for parts with cap. > 600 μ F	Within ± 20 % of initial value						
Leakage current	Shall not exceed 125 % of initial value						

**CAPACITOR ENVIRONMENTAL CHARACTERISTICS**

ITEM	CONDITION	ENVIRONMENTAL CHARACTERISTICS
Humidity tests	At 40 °C/90 % RH 1000 h, no voltage applied.	Capacitance change Cap. \leq 600 μ F Within \pm 10 % of initial value Cap. $>$ 600 μ F Within \pm 20 % of initial value Dissipation factor Not to exceed 150 % of initial + 25 °C requirement
Temperature cycles	At - 55 °C/+ 125 °C, 30 min each, for 5 cycles.	Capacitance change Cap. \leq 600 μ F Within \pm 10 % of initial value Cap. $>$ 600 μ F Within \pm 20 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less
Moisture resistance	MIL-STD-202, method 106 at rated voltage, 42 cycles.	Capacitance change Cap. \leq 600 μ F Within \pm 10 % of initial value Cap. $>$ 600 μ F Within \pm 20 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less
Thermal shock	Capacitors are subjected to 5 cycles of the following: - 55 °C (+ 0 °C, - 5 °C) for 30 min, then + 25 °C (+ 10 °C, - 5 °C) for 5 min, then + 125 °C (+ 3 °C, - 0 °C) for 30 min, then + 25 °C (+ 10 °C, - 5 °C) for 5 min	Capacitance change Cap. \leq 600 μ F Within \pm 10 % of initial value Cap. $>$ 600 μ F Within \pm 20 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less

MECHANICAL PERFORMANCE CHARACTERISTICS

TEST CONDITION	CONDITION	POST TEST PERFORMANCE
Shear test	Apply a pressure load of 5 N for 10 s \pm 1 s horizontally to the center of capacitor side body.	Capacitance change Within \pm 10 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less There shall be no mechanical or visual damage to capacitors post-conditioning.
Substrate bend	With parts soldered onto substrate test board, apply force to the test board for a deflection of 3 mm, for a total of 3 bends at a rate of 1 mm/s.	Capacitance change Within \pm 10 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less
Vibration	MIL-STD-202, method 204, condition D, 10 Hz to 2000 Hz, 20 g peak	Capacitance change Within \pm 10 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less There shall be no mechanical or visual damage to capacitors post-conditioning.
Shock	MIL-STD-202, method 213B shock (specified pulse), condition I, 100 g peak	Capacitance change Within \pm 10 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less There shall be no mechanical or visual damage to capacitors post-conditioning.
Resistance to solder heat	<ul style="list-style-type: none"> Recommended reflow profiles temperatures and durations are located within the Capacitor Series Guides Pb-free and lead-bearing series caps are backward and forward compatible 	Capacitance change Within \pm 10 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less There shall be no mechanical or visual damage to capacitors post-conditioning.
Solderability	MIL-STD-2002, method 208, ANSI/J-STD-002, test B. Applies only to solder and tin plated terminations. Does not apply to gold terminations.	Capacitance change Within \pm 10 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less There shall be no mechanical or visual damage to capacitors post-conditioning.
Resistance to solvents	MIL-STD-202, method 215	Capacitance change Within \pm 10 % of initial value Dissipation factor Initial specified value or less Leakage current Initial specified value or less There shall be no mechanical or visual damage to capacitors post-conditioning.
Flammability	Encapsulant materials meet UL 94 V-0 with an oxygen index of 32 %.	



Guide for Conformal Coated Tantalum Capacitors

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum/tantalum oxide/manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance/volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance/volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS

DIELECTRIC	^e DIELECTRIC CONSTANT
Air or vacuum	1.0
Paper	2.0 to 6.0
Plastic	2.1 to 6.0
Mineral oil	2.2 to 2.3
Silicone oil	2.7 to 2.8
Quartz	3.8 to 4.4
Glass	4.8 to 8.0
Porcelain	5.1 to 5.9
Mica	5.4 to 8.7
Aluminum oxide	8.4
Tantalum pentoxide	26
Ceramic	12 to 400K

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{eA}{t}$$

where

C = Capacitance

e = Dielectric constant

A = Surface area of the dielectric

t = Thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.

SOLID ELECTROLYTE TANTALUM CAPACITORS

Solid electrolyte capacitors contain manganese dioxide, which is formed on the tantalum pentoxide dielectric layer by impregnating the pellet with a solution of manganous nitrate. The pellet is then heated in an oven, and the manganous nitrate is converted to manganese dioxide.

The pellet is next coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the pellet and the can in which it will be enclosed. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for consumer and commercial electronics with the added feature of low cost.

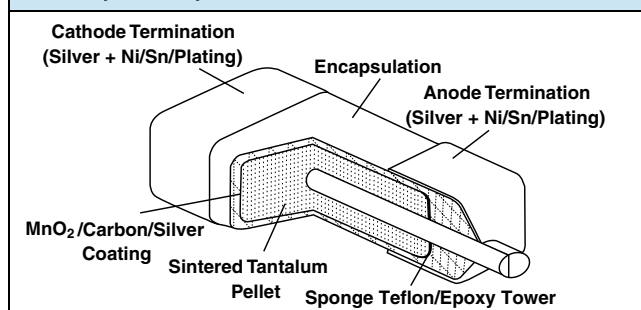
Surface mount designs of "Solid Tantalum" capacitors use lead frames or lead frameless designs as shown in the accompanying drawings.

TANTALUM CAPACITORS FOR ALL DESIGN CONSIDERATIONS

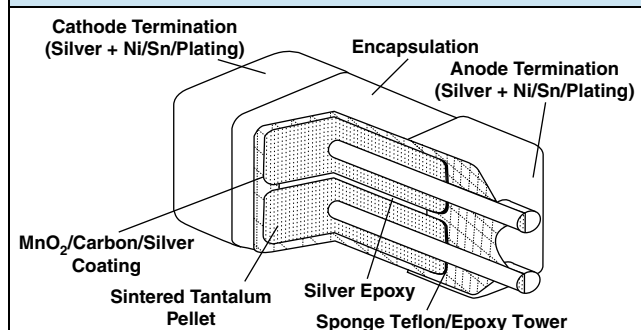
Solid electrolyte designs are the least expensive for a given rating and are used in many applications where their very small size for a given unit of capacitance is of importance. They will typically withstand up to about 10 % of the rated DC working voltage in a reverse direction. Also important are their good low temperature performance characteristics and freedom from corrosive electrolytes.

Vishay Sprague patented the original solid electrolyte capacitors and was the first to market them in 1956. Vishay Sprague has the broadest line of tantalum capacitors and has continued its position of leadership in this field. Data sheets covering the various types and styles of Vishay Sprague capacitors for consumer and entertainment electronics, industry, and military applications are available where detailed performance characteristics must be specified.

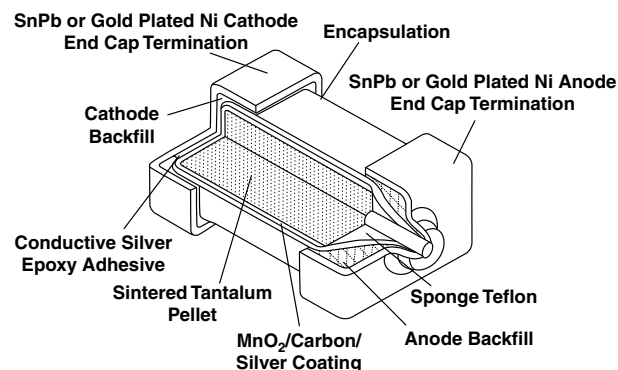
TYPE 195D, 572D, 591D, 592D/W, 594D, 595D, 695D, T95



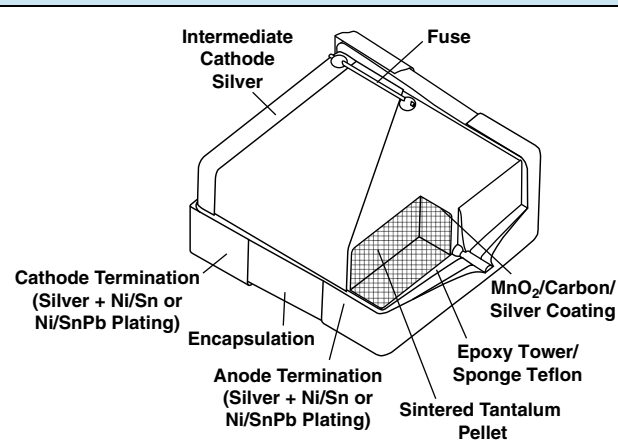
TYPE 597D/T97/13008



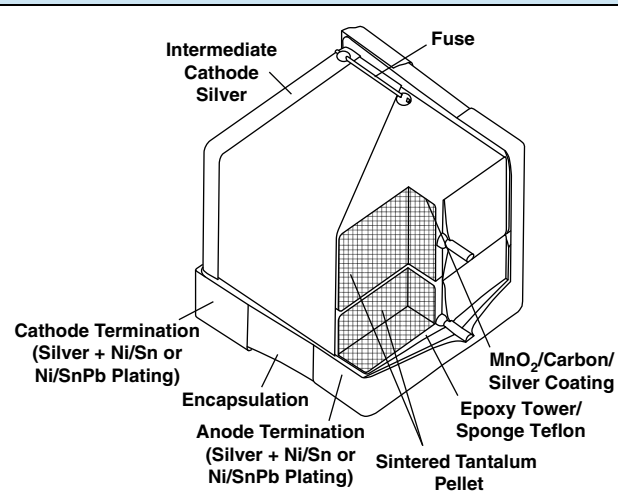
TYPE 194D



TYPE T96



TYPE T98













COMMERCIAL PRODUCTS

SOLID TANTALUM CAPACITORS - CONFORMAL COATED					
SERIES	592W	592D	591D	595D	594D
PRODUCT IMAGE					
TYPE	Surface mount TANTAMOUNT® chip, conformal coated				
FEATURES	Low profile, robust design for use in pulsed applications	Low profile, maximum CV	Low profile, low ESR, maximum CV	Maximum CV	Low ESR, maximum CV
TEMPERATURE RANGE	- 55 °C to + 125 °C (above 40 °C, voltage derating is required)				
CAPACITANCE RANGE	330 µF to 2200 µF	1 µF to 2200 µF	1 µF to 1500 µF	0.1 µF to 1500 µF	1 µF to 1500 µF
VOLTAGE RANGE	6 V to 10 V	4 V to 50 V	4 V to 50 V	4 V to 50 V	4 V to 50 V
CAPACITANCE TOLERANCE	± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %
LEAKAGE CURRENT	0.01 CV or 0.5 µA, whichever is greater				
DISSIPATION FACTOR	14 % to 45 %	4 % to 50 %	4 % to 50 %	4 % to 20 %	4 % to 20 %
CASE CODES	C, M, X	S, A, B, C, D, R, M, X	A, B, C, D, R, M	T, S, A, B, C, D, G, M, R	B, C, D, R
TERMINATION	100 % matte tin	100 % matte tin standard, tin/lead and gold plated available			

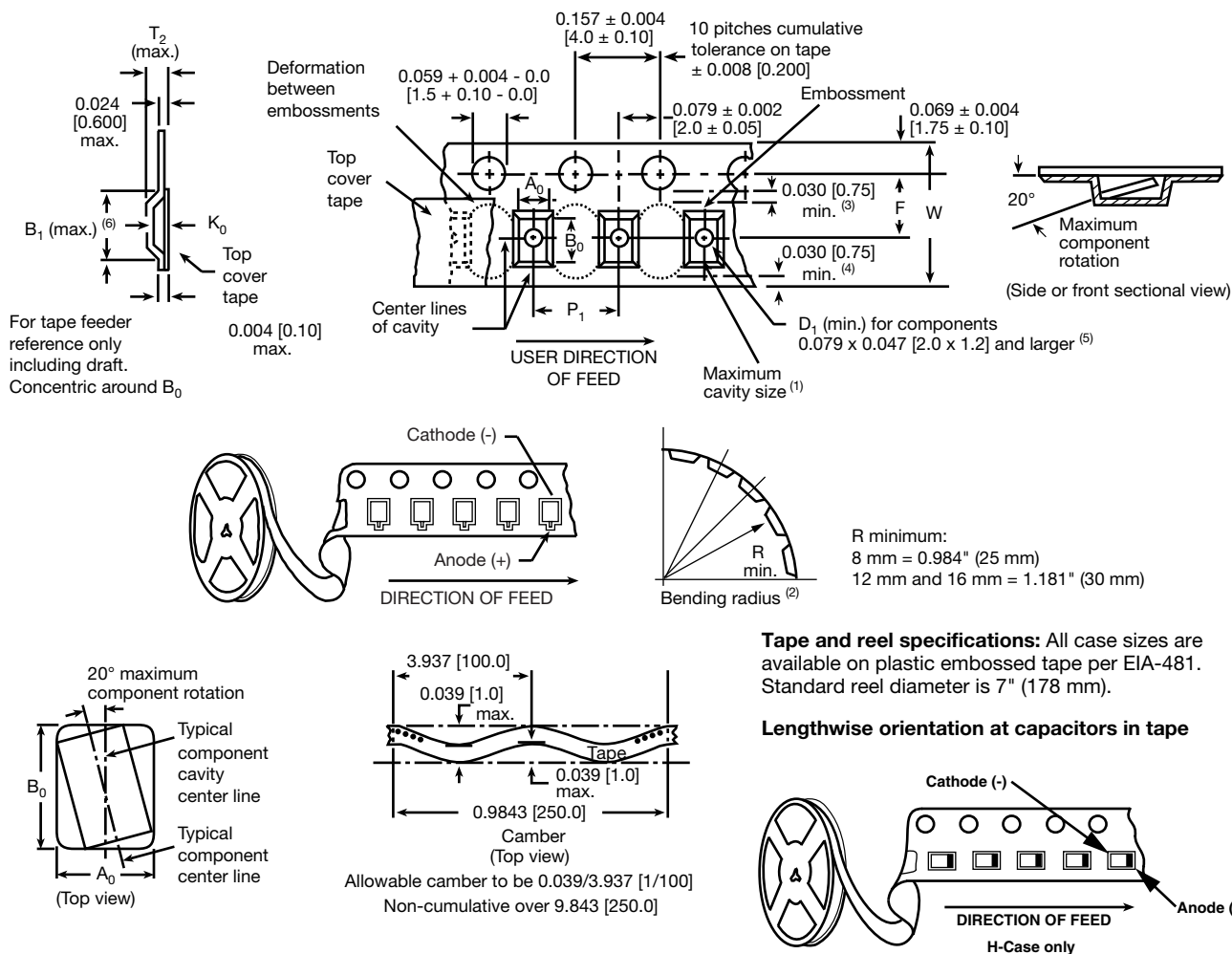
SOLID TANTALUM CAPACITORS - CONFORMAL COATED					
SERIES	597D	572D	695D	195D	194D
PRODUCT IMAGE					
TYPE	TANTAMOUNT® chip, conformal coated				
FEATURES	Ultra low ESR, maximum CV, multi-anode	Low profile, maximum CV	Pad compatible with 194D and CWR06	US and European case sizes	Industrial version of CWR06/CWR16
TEMPERATURE RANGE	- 55 °C to + 125 °C (above 85 °C, voltage derating is required)				
CAPACITANCE RANGE	10 µF to 1500 µF	2.2 µF to 220 µF	0.1 µF to 270 µF	0.1 µF to 330 µF	0.1 µF to 330 µF
VOLTAGE RANGE	4 V to 75 V	4 V to 35 V	4 V to 50 V	2 V to 50 V	4 V to 50 V
CAPACITANCE TOLERANCE	± 10 %, ± 20 %				
LEAKAGE CURRENT	0.01 CV or 0.5 µA, whichever is greater				
DISSIPATION FACTOR	6 % to 20 %	6 % to 26 %	4 % to 8 %	4 % to 8 %	4 % to 10 %
CASE CODES	V, D, E, R, F, Z, M, H	P, Q, S, A, B, T	A, B, D, E, F, G, H	C, S, V, X, Y, Z, R, A, B, D, E, F, G, H	A, B, C, D, E, F, G, H
TERMINATION	100 % matte tin standard, tin/lead solder plated available	100 % matte tin standard, gold plated available	100 % matte tin standard, tin/lead and gold plated available		Gold plated standard; tin/lead solder plated and hot solder dipped available

HIGH RELIABILITY PRODUCTS

SOLID TANTALUM CAPACITORS - CONFORMAL COATED				
SERIES	CWR06	CWR16	CWR26	13008
PRODUCT IMAGE				
TYPE	TANTAMOUNT® chip, conformal coated			
FEATURES	MIL-PRF-55365/4 qualified	MIL-PRF-55365/13 qualified	MIL-PRF-55365/13 qualified	DLA approved
TEMPERATURE RANGE	- 55 °C to + 125 °C (above 85 °C, voltage derating is required)			
CAPACITANCE RANGE	0.10 µF to 100 µF	0.33 µF to 330 µF	10 µF to 100 µF	10 µF to 1500 µF
VOLTAGE RANGE	4 V to 50 V	4 V to 35 V	15 V to 35 V	4 V to 63 V
CAPACITANCE TOLERANCE	± 5 %, ± 10 %, ± 20 %	± 5 %, ± 10 %, ± 20 %	± 5 %, ± 10 %, ± 20 %	± 10 %, ± 20 %
LEAKAGE CURRENT	0.01 CV or 1.0 µA, whichever is greater			0.01 CV or 0.5 µA, whichever is greater
DISSIPATION FACTOR	6 % to 10 %	6 % to 10 %	6 % to 12 %	6 % to 20 %
CASE CODES	A, B, C, D, E, F, G, H	A, B, C, D, E, F, G, H	F, G, H	V, E, F, R, Z, D, M, H, N
TERMINATION	Gold plated; tin/lead; tin/lead solder fused			Tin/lead

SOLID TANTALUM CAPACITORS - CONFORMAL COATED				
SERIES	T95	T96	T97	T98
PRODUCT IMAGE				
TYPE	TANTAMOUNT® chip, Hi-Rel COTS, conformal coated			
FEATURES	High reliability	High reliability, built in fuse	High reliability, ultra low ESR, multi-anode	High reliability, ultra low ESR, built in fuse, multi-anode
TEMPERATURE RANGE	- 55 °C to + 125 °C (above 85 °C, voltage derating is required)			
CAPACITANCE RANGE	0.15 µF to 680 µF	10 µF to 680 µF	10 µF to 1500 µF	10 µF to 1500 µF
VOLTAGE RANGE	4 V to 50 V	4 V to 50 V	4 V to 75 V	4 V to 75 V
CAPACITANCE TOLERANCE	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %
LEAKAGE CURRENT	0.01 CV or 0.5 µA, whichever is greater			
DISSIPATION FACTOR	4 % to 14 %	6 % to 14 %	6 % to 20 %	6 % to 10 %
CASE CODES	A, B, C, D, R, S, V, X, Y, Z	R	V, E, F, R, Z, D, M, H, N	V, E, F, R, Z, M, H
TERMINATION	100 % matte tin, tin/lead			

TAPE AND REEL PACKAGING in inches [millimeters]



Notes

- Metric dimensions will govern. Dimensions in inches are rounded and for reference only.
- ⁽¹⁾ A_0 , B_0 , K_0 , are determined by the maximum dimensions to the ends of the terminals extending from the component body and/or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A_0 , B_0 , K_0) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°.
- ⁽²⁾ Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum.
- ⁽³⁾ This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less.
- ⁽⁴⁾ This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less.
- ⁽⁵⁾ The embossed hole location shall be measured from the sprocket hole controlling the location of the embossment. Dimensions of embossment location shall be applied independent of each other.
- ⁽⁶⁾ B_1 dimension is a reference dimension tape feeder clearance only.



CARRIER TAPE DIMENSIONS in inches [millimeters]						
TAPE WIDTH	W	D ₀	P ₂	F	E ₁	E ₂ min.
8 mm	0.315 + 0.012/- 0.004 [8.0 + 0.3/- 0.1]	0.059 + 0.004/- 0 [1.5 + 0.1/- 0]	0.078 ± 0.0019 [2.0 ± 0.05]	0.14 ± 0.0019 [3.5 ± 0.05]	0.324 ± 0.004 [1.75 ± 0.1]	0.246 [6.25]
12 mm	0.479 + 0.012/- 0.004 [12.0 + 0.3/- 0.1]			0.216 ± 0.0019 [5.5 ± 0.05]		0.403 [10.25]
16 mm	0.635 + 0.012/- 0.004 [16.0 + 0.3/- 0.1]		0.078 ± 0.004 [2.0 ± 0.1]	0.295 ± 0.004 [7.5 ± 0.1]		0.570 [14.25]
24 mm	0.945 ± 0.012 [24.0 ± 0.3]			0.453 ± 0.004 [11.5 ± 0.1]		0.876 [22.25]

CARRIER TAPE DIMENSIONS in inches [millimeters]					
TYPE	CASE CODE	TAPE WIDTH W IN mm	P ₁	K ₀ max.	B ₁ max.
592D 592W 591D	A	8	0.157 ± 0.004 [4.0 ± 0.10]	0.058 [1.47]	0.149 [3.78]
	B	12		0.088 [2.23]	0.166 [4.21]
	C	12	0.315 ± 0.004 [8.0 ± 0.10]	0.088 [2.23]	0.290 [7.36]
	D	12		0.088 [2.23]	0.300 [7.62]
	M	16		0.091 [2.30]	0.311 [7.90]
	R	12		0.088 [2.23]	0.296 [7.52]
	S	8	0.157 ± 0.004 [4.0 ± 0.10]	0.058 [1.47]	0.139 [3.53]
	T	12		0.088 [2.23]	0.166 [4.21]
	X	24	0.472 ± 0.004 [12.0 ± 0.10]	0.011 [2.72]	0.594 [15.1]
595D 594D	A	8	0.157 ± 0.004 [4.0 ± 0.10]	0.063 [1.60]	0.152 [3.86]
	B	12		0.088 [2.23]	0.166 [4.21]
	C	12	0.315 ± 0.004 [8.0 ± 0.10]	0.118 [2.97]	0.290 [7.36]
	D	12		0.119 [3.02]	0.296 [7.52]
	G	12		0.111 [2.83]	0.234 [5.95]
	H	12		0.098 [2.50]	0.232 [5.90]
	M	12	0.157 ± 0.004 [4.0 ± 0.10]	0.085 [2.15]	0.152 [3.85]
	R	12	0.315 ± 0.004 [8.0 ± 0.10]	0.148 [3.78]	0.296 [7.52]
	S	8	0.157 ± 0.004 [4.0 ± 0.10]	0.058 [1.47]	0.149 [3.78]
	T	8		0.054 [1.37]	0.093 [2.36]
695D	A	8	0.157 ± 0.004 [4.0 ± 0.10]	0.058 [1.47]	0.139 [3.53]
	B	12		0.059 [1.50]	0.189 [4.80]
	D	12		0.063 [1.62]	0.191 [4.85]
	E	12		0.074 [1.88]	0.239 [6.07]
	F	12	0.315 ± 0.004 [8.0 ± 0.10]	0.075 [1.93]	0.259 [6.58]
	G	12	0.157 ± 0.004 [4.0 ± 0.10]	0.109 [2.77]	0.301 [7.65]
	H	16	0.315 ± 0.004 [8.0 ± 0.10]	0.124 [3.15]	0.31 [7.87]

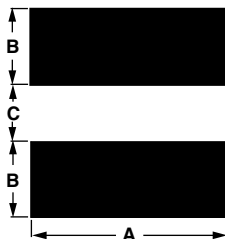


CARRIER TAPE DIMENSIONS in inches [millimeters]					
TYPE	CASE CODE	TAPE WIDTH W IN mm	P ₁	K ₀ max.	B ₁ max.
195D	A	8	0.157 ± 0.004 [4.0 ± 0.10]	0.058 [1.47]	0.139 [3.53]
	B	12		0.059 [1.50]	0.189 [4.80]
	C	8		0.054 [1.37]	0.093 [2.36]
	D	12		0.067 [1.70]	0.179 [4.55]
	E	12		0.074 [1.88]	0.239 [6.07]
	F	12	0.315 ± 0.004 [8.0 ± 0.10]	0.076 [1.93]	0.259 [6.58]
	G	12	0.157 ± 0.004 [4.0 ± 0.10]	0.109 [2.77]	0.301 [7.65]
	H ⁽¹⁾	12	0.472 ± 0.004 [12.0 ± 0.1]	0.122 [3.11]	0.163 [4.14]
	R	12	0.315 ± 0.004 [8.0 ± 0.10]	0.149 [3.78]	0.296 [7.52]
	S	8	0.157 ± 0.004 [4.0 ± 0.10]	0.058 [1.47]	0.149 [3.78]
	V	8		0.060 [1.52]	0.150 [3.80]
	X	12		0.069 [1.75]	0.296 [7.52]
	Y	12		0.089 [2.26]	0.296 [7.52]
	Z	12		0.114 [2.89]	0.288 [7.31]
572D	A	8	0.157 ± 0.004 [4.0 ± 0.10]	0.058 [1.47]	0.149 [3.78]
	B	12		0.087 [2.20]	0.166 [4.21]
	P	8		0.043 [1.10]	0.102 [2.60]
	P	8		0.052 [1.32]	0.106 [2.70]
	Q	8		0.054 [1.37]	0.140 [3.55]
	S	8		0.058 [1.47]	0.149 [3.78]
	T	12		0.061 [1.55]	0.164 [4.16]
194D CWR06 CWR16 CWR26	A	8	0.157 ± 0.004 [4.0 ± 0.10]	0.069 [1.75]	0.139 [3.53]
	B	12		0.073 [1.85]	0.189 [4.80]
	C	12		0.069 [1.75]	0.244 [6.20]
	D	12		0.068 [1.72]	0.191 [4.85]
	E	12	0.315 ± 0.004 [8.0 ± 0.10]	0.074 [1.88]	0.239 [6.07]
	F	12		0.091 [2.31]	0.262 [6.65]
	G	16		0.134 [3.40]	0.289 [7.34]
	H	16		0.129 [3.28]	0.319 [8.10]
597D T97 13008	D	16	0.317 ± 0.004 [8.0 ± 0.10]	0.150 [3.80]	0.313 [7.95]
	E	16		0.173 [4.40]	0.343 [8.70]
	F	16	0.476 ± 0.004 [12.0 ± 0.1]	0.205 [5.20]	0.309 [7.85]
	H	16		0.224 [5.70]	0.313 [7.95]
	M	16		0.193 [4.90]	0.339 [8.60]
	N	16		0.283 [7.20]	0.323 [8.20]
	R	16		0.159 [4.05]	0.313 [7.95]
	V	12	0.317 ± 0.004 [8.0 ± 0.10]	0.088 [2.23]	0.300 [7.62]
	Z	16	0.476 ± 0.004 [12.0 ± 0.1]	0.239 [6.06]	0.311 [7.90]
T95	A	8	0.157 ± 0.004 [4.0 ± 0.10]	0.063 [1.60]	0.152 [3.86]
	B	12		0.088 [2.23]	0.166 [4.21]
	C	12		0.117 [2.97]	0.290 [7.36]
	D	12	0.317 ± 0.004 [8.0 ± 0.10]	0.119 [3.02]	0.296 [7.52]
	R	12		0.149 [3.78]	0.296 [7.52]
	S	8	0.157 ± 0.004 [4.0 ± 0.10]	0.058 [1.47]	0.149 [3.78]
	V	8		0.060 [1.52]	0.150 [3.80]
	X	12		0.069 [1.75]	0.296 [7.52]
	Y	12		0.089 [2.26]	0.296 [7.52]
	Z	12		0.114 [2.89]	0.288 [7.31]
T96	R	16	0.476 ± 0.004 [12.0 ± 0.1]	0.159 [4.05]	0.313 [7.95]
T98	F	16	0.476 ± 0.004 [12.0 ± 0.1]	0.239 [6.06]	0.311 [7.90]
	M	16		0.193 [4.90]	0.339 [8.60]
	Z	16		0.272 [6.90]	0.307 [7.80]

Note
⁽¹⁾ H case only, packaging code T: Lengthwise orientation at capacitors in tape.

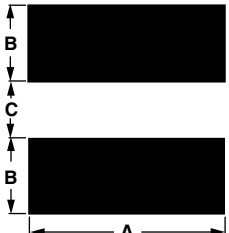


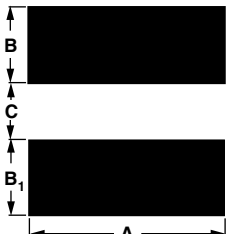
PAD DIMENSIONS in inches [millimeters]



CASE CODE	WIDTH (A)	PAD METALLIZATION (B)	SEPARATION (C)
592D/W - 591D			
A	0.075 [1.9]	0.050 [1.3]	0.050 [1.3]
B	0.118 [3.0]	0.059 [1.5]	0.059 [1.5]
C	0.136 [3.5]	0.090 [2.3]	0.122 [3.1]
D	0.180 [4.6]	0.090 [2.3]	0.134 [3.4]
M	0.256 [6.5]	Anode pad: 0.095 [2.4]	0.138 [3.5]
		Cathode pad: 0.067 [1.7]	
R	0.240 [6.1]	Anode pad: 0.095 [2.4]	0.118 [3.0]
		Cathode pad: 0.067 [1.7]	
S	0.067 [1.7]	0.032 [0.8]	0.043 [1.1]
X	0.310 [7.9]	0.120 [3.0]	0.360 [9.2]
595D - 594D			
T	0.059 [1.5]	0.028 [0.7]	0.024 [0.6]
S	0.067 [1.7]	0.032 [0.8]	0.043 [1.1]
A	0.820 [2.1]	0.050 [1.3]	0.050 [1.3]
B	0.118 [3.0]	0.059 [1.5]	0.059 [1.5]
C	0.136 [3.5]	0.090 [2.3]	0.122 [3.1]
D	0.180 [4.6]	0.090 [2.3]	0.134 [3.4]
G	0.156 [4.05]	0.090 [2.3]	0.082 [2.1]
M	0.110 [2.8]	0.087 [2.2]	0.134 [3.4]
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
195D			
A	0.067 [1.7]	0.043 [1.1]	0.028 [0.7]
B	0.063 [1.6]	0.047 [1.2]	0.047 [1.2]
C	0.059 [1.5]	0.031 [0.8]	0.024 [0.6]
D	0.090 [2.3]	0.055 [1.4]	0.047 [1.2]
E	0.090 [2.3]	0.055 [1.4]	0.079 [2.0]
F	0.140 [3.6]	0.063 [1.6]	0.087 [2.2]
G	0.110 [2.8]	0.059 [1.5]	0.126 [3.2]
H	0.154 [3.9]	0.063 [1.6]	0.140 [3.6]
N	0.244 [6.2]	0.079 [2.0]	0.118 [3.0]
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
S	0.079 [2.0]	0.039 [1.0]	0.039 [1.0]
V	0.114 [2.9]	0.039 [1.0]	0.039 [1.0]
X	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]
Y	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]
Z	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]

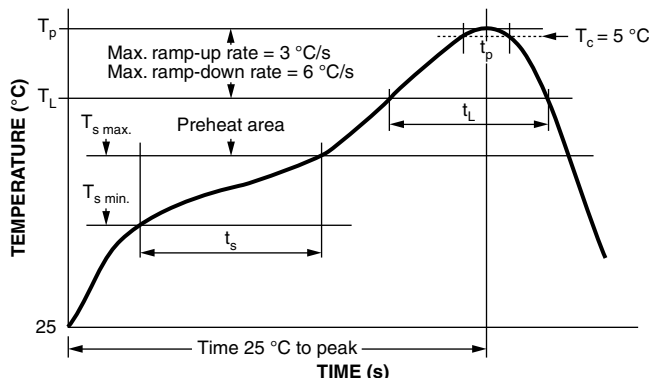


PAD DIMENSIONS in inches [millimeters]			
			
CASE CODE	WIDTH (A)	PAD METALLIZATION (B)	SEPARATION (C)
CWR06/CWR16/CWR26 - 194D - 695D			
A	0.065 [1.6]	0.50 [1.3]	0.040 [1.0]
B	0.065 [1.6]	0.70 [1.8]	0.055 [1.4]
C	0.065 [1.6]	0.70 [1.8]	0.120 [3.0]
D	0.115 [2.9]	0.70 [1.8]	0.070 [1.8]
E	0.115 [2.9]	0.70 [1.8]	0.120 [3.0]
F	0.150 [3.8]	0.70 [1.8]	0.140 [3.6]
G	0.125 [3.2]	0.70 [1.8]	0.170 [4.3]
H	0.165 [4.2]	0.90 [2.3]	0.170 [4.3]
T95			
B	0.120 [3.0]	0.059 [1.5]	0.059 [1.5]
C	0.136 [3.5]	0.090 [2.3]	0.120 [3.1]
D	0.180 [4.6]	0.090 [2.3]	0.136 [3.47]
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
S	0.080 [2.03]	0.040 [1.02]	0.040 [1.02]
V	0.114 [2.9]	0.040 [1.02]	0.040 [1.02]
X, Y, Z	0.114 [2.9]	0.065 [1.65]	0.122 [3.1]
T96			
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
597D - T97 - T98 - 13008			
D, E, V	0.196 [4.9]	0.090 [2.3]	0.140 [3.6]
F, R, Z	0.260 [6.6]	0.090 [2.3]	0.140 [3.6]
M, H, N	0.284 [7.2]	0.090 [2.3]	0.140 [3.6]

PAD DIMENSIONS in inches [millimeters]				
				
CASE CODE	WIDTH (A)	PAD METALLIZATION (B)	PAD METALLIZATION (B ₁)	SEPARATION (C)
572D				
A	0.079 [2.0]	0.039 [1.0]	0.035 [0.9]	0.047 [1.2]
Q	0.079 [2.0]	0.039 [1.0]	0.035 [0.9]	0.047 [1.2]
S	0.079 [2.0]	0.039 [1.0]	0.035 [0.9]	0.047 [1.2]
B	0.110 [2.8]	0.039 [1.0]	0.035 [0.9]	0.055 [1.4]
P	0.055 [1.4]	0.024 [0.6]	0.024 [0.6]	0.035 [0.9]
T	0.110 [2.8]	0.035 [0.9]	0.031 [0.8]	0.055 [1.4]

RECOMMENDED REFLOW PROFILES

Capacitors should withstand Reflow profile as per J-STD-020 standard



PROFILE FEATURE	SnPb EUTECTIC ASSEMBLY	LEAD (Pb)-FREE ASSEMBLY
Preheat/soak		
Temperature min. ($T_{s \min.}$)	100 °C	150 °C
Temperature max. ($T_{s \max.}$)	150 °C	200 °C
Time (t_s) from ($T_{s \min.}$ to $T_{s \max.}$)	60 s to 120 s	60 s to 120 s
Ramp-up		
Ramp-up rate (T_L to T_p)	3 °C/s max.	3 °C/s max.
Liquidous temperature (T_L)	183 °C	217 °C
Time (t_L) maintained above T_L	60 s to 150 s	60 s to 150 s
Peak package body temperature (T_p)	Depends on type and case – see table below	
Time (t_p)* within 5 °C of the specified classification temperature (T_c)	20 s	30 s
Ramp-down		
Ramp-down rate (T_p to T_L)	6 °C/s max.	6 °C/s max.
Time 25 °C to peak temperature	6 min max.	8 min max.

PEAK PACKAGE BODY TEMPERATURE (T_p)

TYPE/CASE CODE	PEAK PACKAGE BODY TEMPERATURE (T_p)	
	SnPb EUTECTIC PROCESS	LEAD (Pb)-FREE PROCESS
591D/592D - all cases, except X25H, M and R cases	235 °C	260 °C
591D/592D - X25H, M and R cases	220 °C	250 °C
594D/595D - all cases except C, D and R	235 °C	260 °C
594D/595D - C, D and R case	220 °C	250 °C
572D all cases	n/a	260 °C
T95 B, S, V, X, Y cases	235 °C	260 °C
T95 C, D, R and Z cases	220 °C	250 °C
T96 R case	220 °C	250 °C
195D all cases, except G, H, R and Z	235 °C	260 °C
195D G, H, R and Z cases	220 °C	250 °C
695D all cases, except G and H cases	235 °C	260 °C
695D G, H cases	220 °C	250 °C
597D, T97, T98 all cases, except V case	220 °C	250 °C
597D, T97, T98 V case	230 °C	260 °C
194D all cases, except H and G cases	235 °C	260 °C
194D H and G cases	220 °C	250 °C

**GUIDE TO APPLICATION**

1. **AC Ripple Current:** The maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = Power dissipation in W at + 25 °C as given in the tables in the product datasheets (Power Dissipation).

R_{ESR} = The capacitor equivalent series resistance at the specified frequency

2. **AC Ripple Voltage:** The maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

or, from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = Power dissipation in W at + 25 °C as given in the tables in the product datasheets (Power Dissipation).

R_{ESR} = The capacitor equivalent series resistance at the specified frequency

Z = The capacitor impedance at the specified frequency

- 2.1 The sum of the peak AC voltage plus the applied DC voltage shall not exceed the DC voltage rating of the capacitor.
- 2.2 The sum of the negative peak AC voltage plus the applied DC voltage shall not allow a voltage reversal exceeding 10 % of the DC working voltage at + 25 °C.
3. **Reverse Voltage:** Solid tantalum capacitors are not intended for use with reverse voltage applied. However, they have been shown to be capable of withstanding momentary reverse voltage peaks of up to 10 % of the DC rating at 25 °C and 5 % of the DC rating at + 85 °C.
4. **Temperature Derating:** If these capacitors are to be operated at temperatures above + 25 °C, the permissible RMS ripple current or voltage shall be calculated using the derating factors as shown:

TEMPERATURE	DERATING FACTOR
+ 25 °C	1.0
+ 85 °C	0.9
+ 125 °C	0.4

5. **Power Dissipation:** Power dissipation will be affected by the heat sinking capability of the mounting surface. Non-sinusoidal ripple current may produce heating effects which differ from those shown. It is important that the equivalent I_{RMS} value be established when calculating permissible operating levels. (Power dissipation calculated using derating factor (see paragraph 4)).

6. **Attachment:**

- 6.1 **Soldering:** Capacitors can be attached by conventional soldering techniques, convection, infrared reflow, wave soldering and hot plate methods. The soldering profile chart shows typical recommended time/temperature conditions for soldering. Preheating is recommended to reduce thermal stress. The recommended maximum preheat rate is 2 °C/s. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor.

7. **Recommended Mounting Pad Geometries:** The nib must have sufficient clearance to avoid electrical contact with other components. The width dimension indicated is the same as the maximum width of the capacitor. This is to minimize lateral movement.

8. **Cleaning (Flux Removal) After Soldering:** TANTAMOUNT® capacitors are compatible with all commonly used solvents such as TES, TMS, Prelete, Chlorethane, Terpene and aqueous cleaning media. However, CFC/ODS products are not used in the production of these devices and are not recommended. Solvents containing methylene chloride or other epoxy solvents should be avoided since these will attack the epoxy encapsulation material.



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